

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	149480	light near emitting near (device or diode or element)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
2	BRS	L15	12036	hydrogen near concentration	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
3	BRS	L22	157	11 and 115	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
4	BRS	L8	4	(p-type near5 GaN) same (hydrogen near concentration)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
5	BRS	L29	28	122 and GaN	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B

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